

SILICON TRANSISTOR 2SA1897

PNP SILICON EPITAXIAL TRANSISTOR FOR LOW-FREQUENCY POWER AMPLIFIERS AND MID-SPEED SWITCHING

The 2SA1897 features a low saturation voltage and is available for high current control in small dimension. This transistor is ideal for high efficiency DC/DC converters due to fast switching speed.

FEATURES

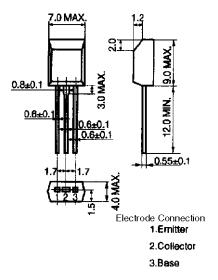
- · High current capacitance
- · Low collector saturation voltage and high hee
- · Insulation type package supportable for radial taping

QUALITY GRADES

Standard

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

PACKAGE DRAWING (UNIT: mm)



ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	Vсво		-30	V
Collector to emitter voltage	VCEO		-20	V
Emitter to base voltage	VEBO		-10	V
Collector current (DC)	Ic(DC)	Tc = 25°C	-5.0	Α
Collector current (pulse)	IC(pulse)	PW ≤ 10 ms, duty cycle ≤ 50 % Tc = 25°C	-8.0	А
Base current (DC)	I _{B(DC)}		-0.5	Α
Total power dissipation	Рт		1.0	W
Total power dissipation	Рт	Tc = 25°C	6.0	W
Junction temperature	Tj		150	°C
Storage temperature	Tstg		-55 to +150	°C

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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

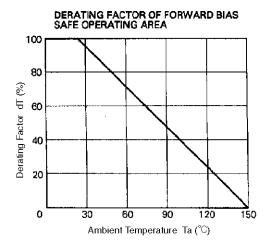
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	VcB = -20 V, IE = 0			1.0	μΑ
Emitter cutoff current	ІЕВО	V _{EB} = -8.0 V, I _C = 0			1.0	μΑ
DC current gain	h _{FE1}	Vce = -2.0 V, Ic = -0.5 A	200		600	-
DC current gain	h _{FE2}	Vce = -2.0 V, Ic = -4.0 A	160			-
Collector saturation voltage	V _{CE(sat)}	$I_C = -4.0 \text{ A}, I_B = -50 \text{ mA}$		-230	-250	mV
Base saturation voltage	V _{BE(sat)}	$I_C = -4.0 \text{ A}, I_B = -50 \text{ mA}$		-0.9	-1.2	V
Gain bandwidth product	f⊤	Vce = -5.0 V, IE = 1.5 A		180		MHz
Output capacitance	Сор	VcB = −10 V, IE = 0, f = 1.0 MHz		220		pF
Turn-on time	ton	Ic = -5.0 A, Vcc = -10 V		400		ns
Storage time	t stg	$I_{B1} = -I_{B1} = -125 \text{ mA},$ $R_L = 2.0 \Omega,$		300		ns
Fall time	tf	111. – 2.0 32,		60		ns

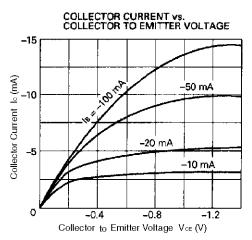
hfe CLASSIFICATION

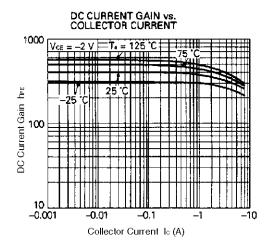
Marking	L	К
h _{FE1}	200 to 400	300 to 600

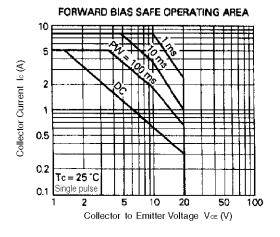


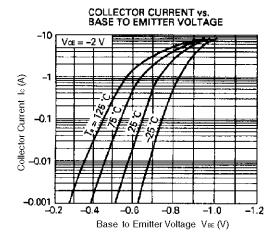
TYPICAL CHARACTERISTICS (Ta = 25°C)

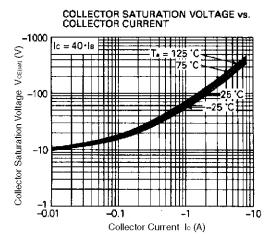




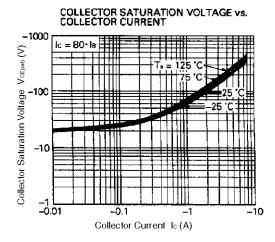


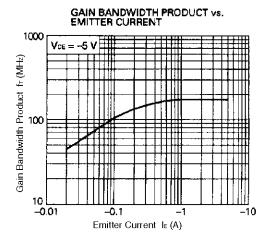


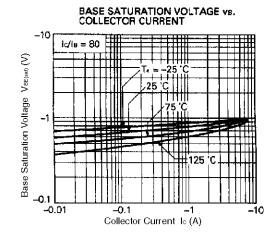


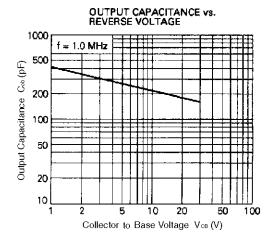


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